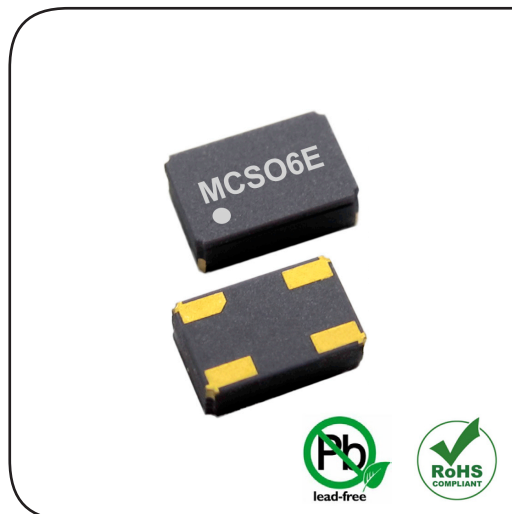
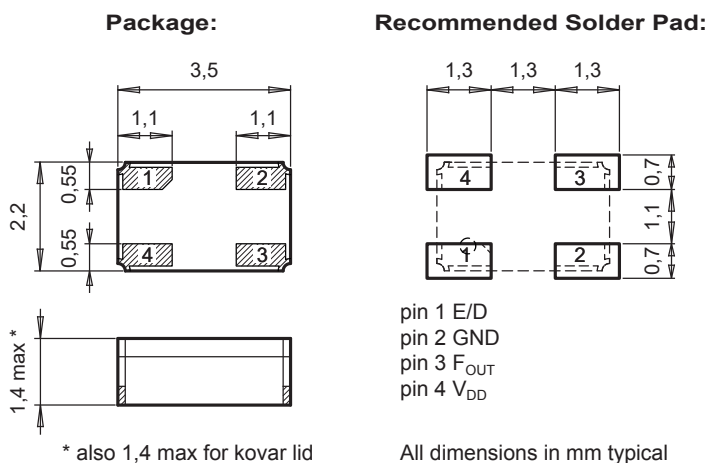


MCSO6E

High Temp Clock Oscillator 15 kHz – 60 MHz



DIMENSIONS



APPLICATIONS

Security / Safety
Avionics / Aerospace
Radio Communication
Geothermal Equipment
Remote Control / Telemetry
Down Hole and Well Drilling

DESCRIPTION

The MCSO6E is a High Temperature, High Frequency SMD Oscillator that incorporates an integrated HCMOS circuit together with an XTAL. It operates under vacuum in a hermetically sealed ceramic package.

FEATURES

Outstanding hermetic sealing with gold-tin preform.
High stability and low aging guaranteed by hermetic sealing.
Frequency stability guaranteed for 1000 h at T_{MAX}.
Very fast start-up.
Operates in fundamental mode.
High shock and vibration resistant.
100% Pb-free, RoHS-compliant.

ELECTRICAL CHARACTERISTICS AT 25°C

Overall frequency stability over temperature range C = -55 to +125°C E = -55 to +150°C D = -55 to +175°C G = -55 to +210°C	¹⁾ ΔF/F	≤ ±100 ≤ ±150 ≤ ±300 ≤ ±400	ppm
Supply voltage ±5%	³⁾ V _{DD}	2.5 / 3.3 / 5.0	V
Input current	I _{DD}	See I _{DD} table	
Output signal		HCMOS compatible	
F _{OUT} duty cycle @ V _{DD} /2 (min./max.)	δ _{FOUT}	40 / 60	%
Rise & fall time For L version, t _r / t _f ≤ 25 ns (C _L = 15 pF, 20% to 80% V _{DD})	t _r / t _f	≤ 7	ns
Output level V _{OL} / V _{OH}		< 0.4 / > V _{DD} - 0.5	V
Start-up time	t _{START}	< 5	ms
Capacitive load min. / max. For L version, C _L max. = 27 pF	C _L	3 / 47	pF

1) Including adjustment at +25°C, long term aging 1000 h at T_{MAX}, V_{DD} variations ±5% and C_L variations min. to max.

2) For the low consumption version (L), G version is only available as 5.0 V version and the G range is limited to +200°C

3) A 47 nF decoupling capacitor has to be connected between V_{DD} and GND

INPUT CURRENT: I_{DD} (no load)
(For L version, $C_L = 10$ pF)

STANDARD FREQUENCIES

ENABLE/DISABLE E/D, OPTION 1

ENVIRONMENTAL CHARACTERISTICS

TERMINATIONS AND PROCESSING, OPTION 2

ORDERING INFORMATION

Frequency	32.768 kHz (L)	≤ 10 MHz	≤ 20 MHz	> 20 to 60 MHz
$V_{DD} = 2.5$ V (W)	< 100 μ A	< 2 mA	< 3 mA	< 15 mA
$V_{DD} = 3.3$ V (V)	< 110 μ A	< 4 mA	< 5 mA	< 20 mA
$V_{DD} = 5.0$ V (Blank)	< 120 μ A	< 6 mA	< 7 mA	< 30 mA

Frequencies				
32.768 kHz	3.6864 MHz	4.0000 MHz	8.0000 MHz	10.0000 MHz
12.0000 MHz	12.8000 MHz	14.7456 MHz	16.0000 MHz	20.0000 MHz
24.0000 MHz				
L version: Other frequencies from 15 kHz to 100 kHz on request Standard version: Other frequencies from 100 kHz to 60 MHz on request				

Input level V_{IL} / V_{IH}		$< 0.3 V_{DD} / > 0.7 V_{DD}$	V
Reaction time, Standard version	t	< 1	μ s
Reaction time, L version	t	< 5	ms

Pin 1 E/D	Pin 3 F _{OUT}
V_{IH} or open	Output enabled
V_{IL}	Output disabled (Hi-Z)

No E/D function before V_{DD} is set.

	Conditions
Storage temperature range	-65 to $+125^{\circ}\text{C}$
Shock resistance (survival)	10000 g, 0.3 ms, $\frac{1}{2}$ sine
Vibration resistance (survival)	80 g / 10 – 2000 Hz

Reflow per IPC/JEDEC J-STD-020C	$260^{\circ}\text{C} / 20 - 40$ s
Package	Ceramic
Lid	Ceramic lid (Kovar lid on G range version)
Terminations (Option 2) (T3 not available for G range)	SnAgCu solder dipped pads (T3) Au flashed pads (Blank)

MCS06E	V – D	24.000 MHz	E/D	T3	XXX
L = Low power Blank = Standard Supply voltage W = $V_{DD} = 2.5$ V V = $V_{DD} = 3.3$ V Blank = $V_{DD} = 5.0$ V Temperature range C = -55 to $+125^{\circ}\text{C}$ E = -55 to $+150^{\circ}\text{C}$ D = -55 to $+175^{\circ}\text{C}$ G = -55 to $+210^{\circ}\text{C}$ * X = Custom					
Frequency Option 1 E/D = Enable/Disable Blank = No function Option 2 T3 = SnAgCu solder dipped pads ** Blank = Au flashed pads Customer specification N°					
* For the low consumption version (L), G version is only available as 5.0 V version and the G range is limited to $+200^{\circ}\text{C}$. Kovar lid on G range version. ** T3 not available for G range version.					
A unique part number will be generated for each product specification, i.e: 20xxxx-MG00 ≥ 250 pcs (in 12 mm tape on 7" reel) 20xxxx-EA00 yyy pcs (in ESD plastic tray)					

All specifications subject to change without notice.